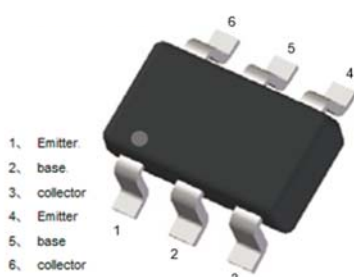
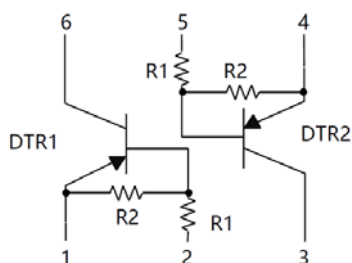


Dual PNP Digital Transistors (Built-in Resistors)



Features

- Moisture sensitivity level 1
- Halogen free and RoHS compliant
- Surface mount package ideally suited for automatic insertion

Application

- Signal amplification
- Switching circuit

Mechanical data

- **Package:** SOT-363S
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102

■ Maximum Ratings ($T_a=25^{\circ}\text{C}$ Unless otherwise specified)

Item	Symbol	Unit	Conditions	Value
Device marking code				B16
Collector-base voltage	V_{CC}	V		-50
Collector-emitter voltage	V_{IN}	V		-40 to +10
Collector current	I_O	mA		-100
Power dissipation	P_D	mW		150
Operation junction temperature	T_J	$^{\circ}\text{C}$		-55 to +150
Storage temperature	T_{STG}	$^{\circ}\text{C}$		-55 to +150



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■ Electrical Characteristics (T_a=25°C Unless otherwise specified)

Item	Symbol	Unit	Conditions	Min	Typ	Max
Input voltage	V _{I(off)}	V	V _{CC} =-5V, I _c =-100uA	-0.4		
	V _{I(on)}	V	V _O =-0.3V, I _c =-2mA			-2.5
Output voltage	V _{O(on)}	V	I _o / I _i = -10mA/-0.5 mA			-0.3
Input current	I _I	mA	V _I =-5V			-0.36
Output current	I _{O(off)}	uA	V _{CC} =-50V, V _i =0			-0.5
DC current gain	G _I		V _O =-5V, I _o =-5mA	68		
Input resistance	R ₁	kΩ		15.4	22	28.6
Resistance ratio	R ₂ /R ₁			1.7	2.1	2.6
Transition frequency	f _T	MHz	V _O =-10V, I _o =-5mA, f=100MHz		250	

■ Thermal Characteristics

Parameter	Symbol	Unit	Value
Thermal resistance, junction-to-ambient	R _{θJ-A} ⁽¹⁾	°C/W	834
Thermal resistance, junction-to-case	R _{θJ-C} ⁽¹⁾	°C/W	667

Note:

(1) Device mounted on PCB, single-sided copper, with standard footprint.

■ Ordering Information

Preferred P/N	Packing code	Unit weight(g)	Minimum package(pcs)	Inner box quantity(pcs)	Outer carton quantity(pcs)	Delivery mode
UMB16NS	F2	Approximate 0.009	3000	30000	120000	7" reel
UMB16NS	F3	Approximate 0.009	10000	/	210000	7" reel



■Characteristics

Fig 1: Input Voltage (On) Characteristics

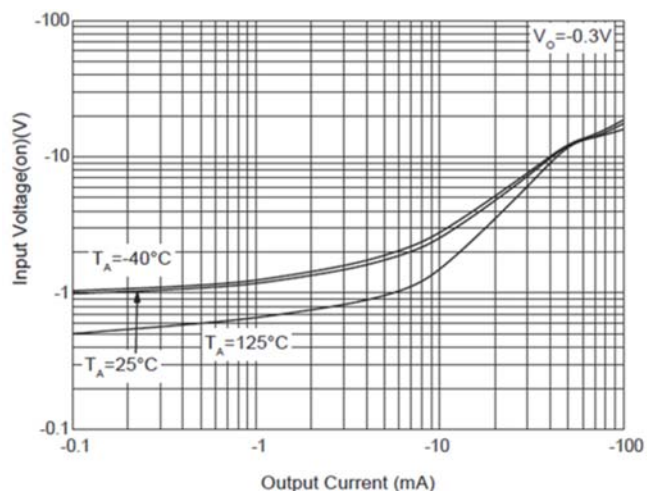


Fig 2: Input Voltage (Off) Characteristic

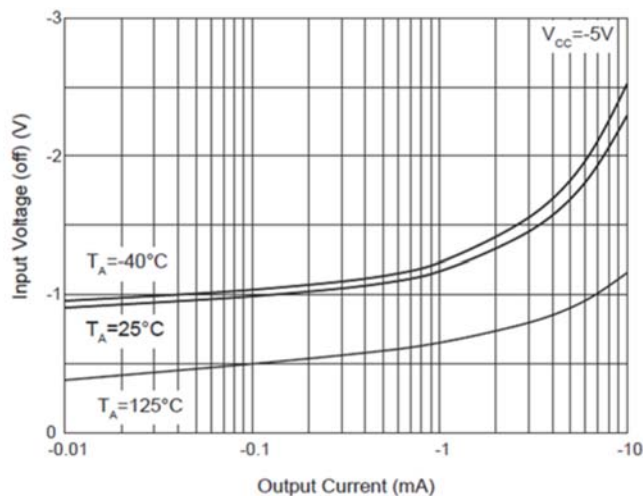


Fig 3: DC Current Gain Characteristics

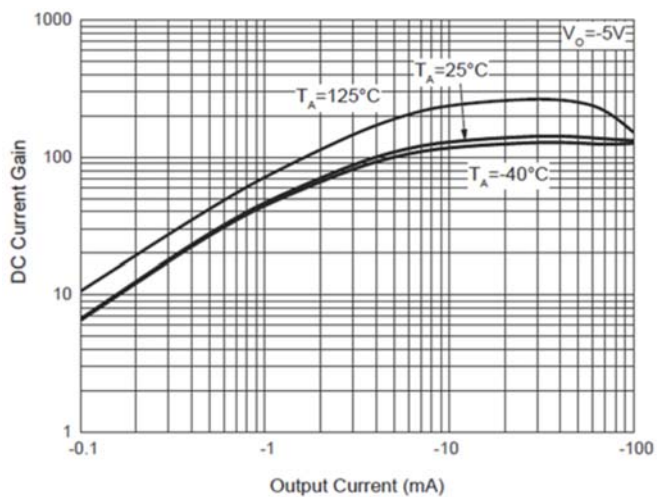


Fig 4: Output Voltage Characteristics

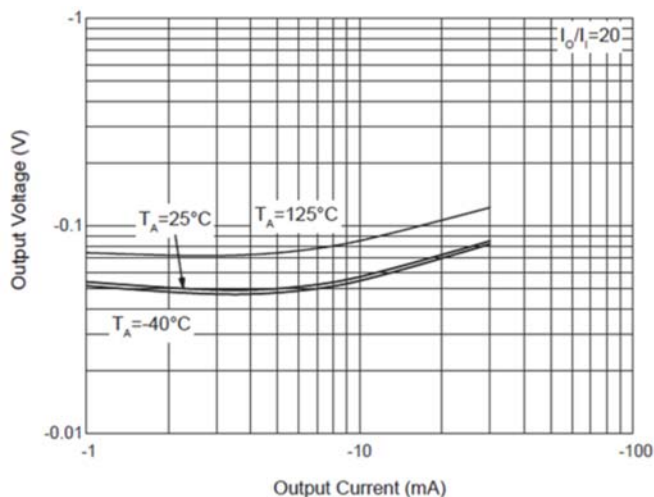
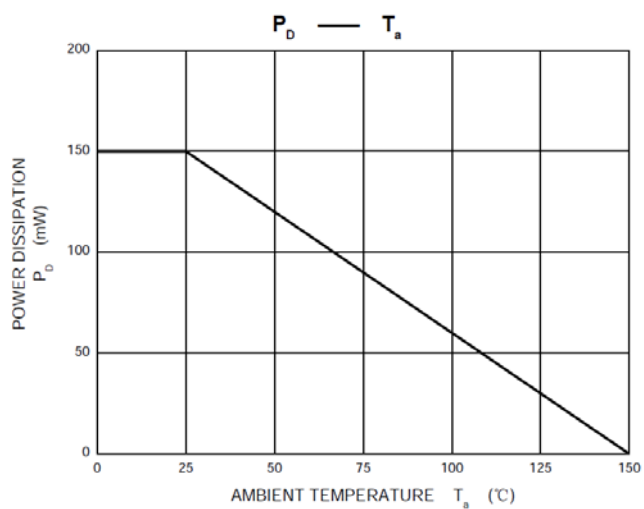


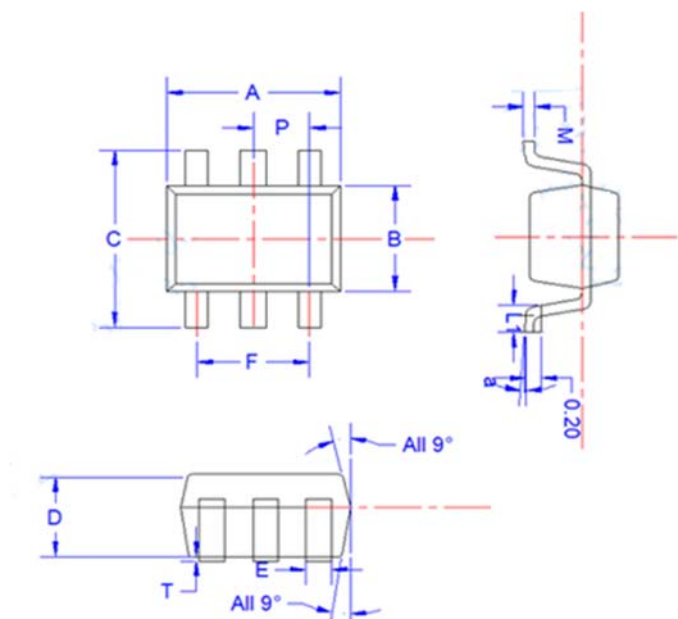
Fig 5: P_D-T_a Curve





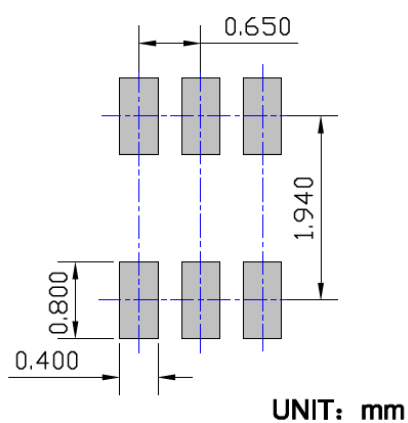
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■ Outline Dimensions



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
E	0.15	0.25	0.35
B	1.15	1.25	1.35
C	2.00	2.10	2.20
P	0.650BSC		
A	1.80	2.00	2.20
T	0.00	0.05	0.100
D	0.90	0.95	1.00
L1	0.20	0.30	0.40
a	4°±4°		
M	0.10	0.15	0.25

■ Suggested Pad Layout





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